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IN THE UNITED STATES PATENT & TRADEMARK OFFICE

IN RE APPLICATION OF :
TATSUYA OHGURO : EXAMINER: FARAHANI, D.
SERIAL NO: 10/084,148 :
FILED: FEBRUARY 28, 2002 : GROUP ART UNIT: 2814
FOR: SEMICONDUCTOR DEVICE :
APPLIED TO A VARIABLE
CAPACITANCE CAPACITOR AND
AMPLIFIER

AMENDMENT UNDER 37 C.F.R. § 1.114

COMMISSIONER FOR PATENTS
ALEXANDRIA, VIRGINIA 22313

SIR:

Further in response to the Office Action dated December 11, 2002 and the Advisory
Action dated April 3, 2003, please amend the above-identified application as follows:

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IN THE CLAIMS

✓
Please cancel without prejudice Claims 3, 9 and 14.

**Please amend Claims 1, 7, 13, and 16 as shown in clean form below. A marked
up copy of the amended claims is attached.**

--1. (Amended) A semiconductor device comprising:

a semiconductor substrate;

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a first conductivity type well area formed in a surface area of the semiconductor
substrate;

a plurality of element isolation areas formed in the well area;